# **RPI-579N1E**

## Photointerrupter, General type

### Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limits	Unit
Input (LED)	Forward current	lF	35	mA
	Reverse voltage	VR	5	V
	Power dissipation	Po	70	mW
Output (photo- (transistor)	Collector-emitter voltage	Vceo	30	V
	Emitter-collector voltage	VECO	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		Tstg	-40 to +85	°C
	Soldering temperture	Tsol	260 / 3 *	°C / s

\* 1mm from the body bottom.

#### Electrical and optical characteristics (Ta=25°C)

Parameter			Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage		VF	-	1.4	1.7	V	IF=10mA
	Reverse current		IR	-	-	10	μΑ	Vr=5V
Output charac- teristics	Dark current		ICEO	-	-	0.5	μΑ	Vce=10V
	Peak sensitivity wavelength		λρ	-	800	-	nm	-
Transfer characteristics	Collector current		lc	0.5	-	-	mA	Vce=5V, IF=10mA
	Collector-emitter saturation voltage		VCE(sat)	Ι	0.1	0.5	V	IF=10mA, Ic=0.1mA
	Response time	Rise time	tr	I	10	-	μs	Vcc=5V, IF=10mA, RL=100Ω
		Fall time	tf	-	10	-	μs	
Infrared light emitter diode	Peak light emitting wavelength		λp	-	850	_	nm	IF=10mA * Non-coherent Infrared light emitting diode used.
Photo transistor	Response time		tr∙tf	-	10	_	μs	Vcc=5V, lc=1mA, RL=100 $\Omega$ * This product is not designed to be protected against electromagnetic wave.
	Maximum sensitivity wavelength		λp	-	800	-	nm	_

#### Electrical and optical characteristics curves

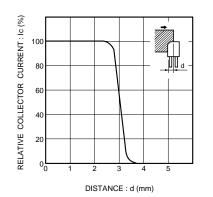


Fig.1 Relative output vs. distance (I)

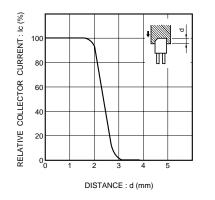
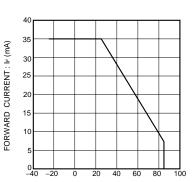


Fig.4 Relative output vs. distance (II)



AMBIENT TEMPERATURE : Ta (°C)

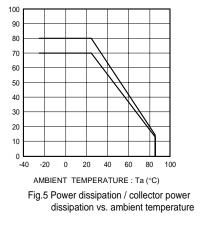
Fig.2 Forward current falloff

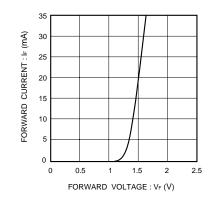
Р

S

DIS

POWER DISSIPATION





Applications

AV equipment

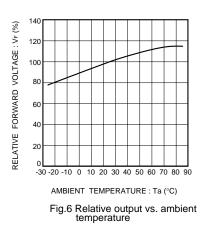
Features

3) Quick response time.

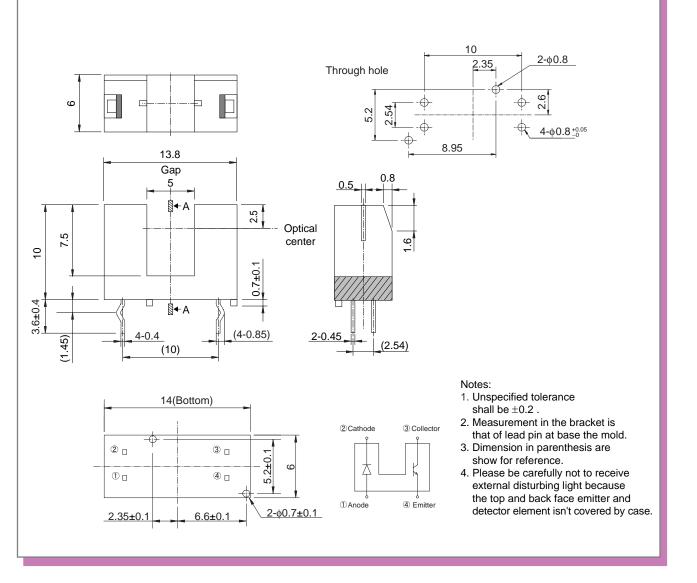
2) Small gap (0.5mm) and good accuracy.

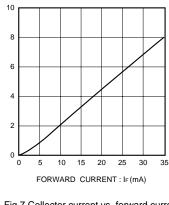
4) Filter against visible ray is built-in.5) Kinked forming.

#### Fig.3 Forward current vs. forward voltage



Dimensions (Unit : mm)





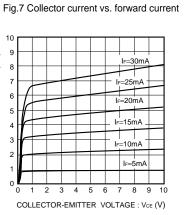
CURRENT

R

COLLECT

7

Ы



t₀: Delav time

TIME

ONSE

R

20

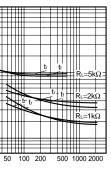
Input

×

Vcc

=:K

≷ R∟



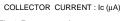


Fig.8 Response time vs. collector current

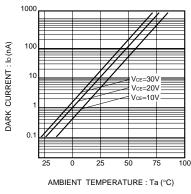
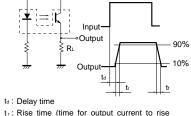


Fig.9 Dark current vs. ambient temperature



from 10% to 90% of peak current) tr: Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time measurement circuit

#### Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
  product described in this document are for reference only. Upon actual use, therefore, please request
  that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
  otherwise dispose of the same, no express or implied right or license to practice or commercially
  exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact your nearest sales office.

### **ROHM** Customer Support System

THE AMERICAS / EUROPE / ASIA / JAPAN

#### www.rohm.com

Contact us : webmaster @ rohm.co.jp

Copyright © 2008 ROHM CO.,LTD. ROHM CO., LTD. 21 Saiin Mizosaki-cho, Ukyo-ku, Kyoto 615-8585, Japan TEL : +81-75-311-2121 FAX : +81-75-315-0172

Appendix1-Rev2.0

rohm

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ROHM Semiconductor: <u>RPI-579N1E</u>